

Quad 2-Input NAND Gate with Schmitt-Trigger Inputs High-Performance Silicon-Gate CMOS

Features

Output Drive Capability: 10 LSTTL Loads

Outputs Directly Interface to CMOS, NMOS, and TTL

Operating Voltage Range: 2.0 to 6.0 V

Low Input Current: 1.0 μA

High Noise Immunity Characteristic of CMOS Devices

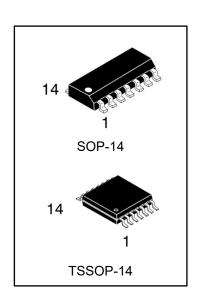
 In Compliance with the Requirements as Defined by JEDEC Standard No. 7A

• ESD Performance:

HBM > 2000 V; Machine Model > 200 V

Chip Complexity: 72 FETs or 18 Equivalent Gates

These are Pb-Free Device



ORDERING INFORMATION

| DEVICE | Package Type | MARKING | Packing | Packing Qty |
|--------------|--------------|---------|---------|--------------|
| 74HC132M/TR | SOP-14 | 74HC132 | REEL | 2500pcs/reel |
| 74HC132MT/TR | TSSOP-14 | HC132 | REEL | 2500pcs/reel |



GENERAL DESCRIPTION

The 74HC132 is identical in pinout to the LS132. The device nputs are compatible with standard CMOS outputs; with pull-up resistors, they are compatible with LSTTL outputs. The HC132 can be used to enhance noise immunity or to square up slowly changing waveforms.

PIN CONFIGURATION

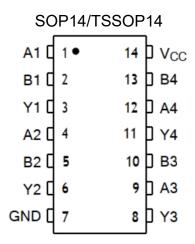
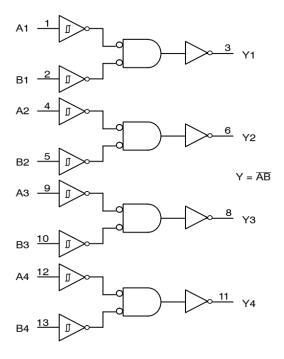


Figure 1. Pin Assignment



PIN 14 = V_{CC}:

PIN 7 = GND

Figure 2. Logic Diagram



FUNCTION TABLE

| Inputs | | Output |
|--------|---|--------|
| Α | В | Υ |
| L | L | Н |
| L | Н | Н |
| H | L | Н |
| H | Н | L |

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|----------|---|----------------|------|
| Vcc | Positive DC Supply Voltage | -0.5 to +7.0 | V |
| VIN | Digital Input Voltage | -0.5 to +7.0 | V |
| Vout | DC Output Voltage Output in 3-State | -0.5 to +7.0 | V |
| | High or Low State | -0.5toVCC +0.5 | |
| lık | Input Diode Current | -20 | mA |
| lok | Output Diode Current | ±20 | mA |
| lout | DC Output Current, per Pin | ±25 | mA |
| ICC | DC Supply Current, VCC and GND Pins | ±75 | mA |
| IGND | DC Ground Current per Ground Pin | ±75 | mA |
| TSTG | Storage Temperature Range | -65 to +150 | °C |
| TL | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | °C |
| TJ | Junction Temperature Under Bias | +125 | °C |
| θЈА | Thermal Resistance 14-SOP | 125 | °C/W |
| | 14-TSSOP | 170 | |
| PD | Power Dissipation in Still Air at 85°C SOP | 500 | mW |
| | TSSOP | 450 | |
| MSL | Moisture Sensitivity | Level 1 | |
| FR | Flammability Rating Oxygen Index: 30% - 35% | UL 94 V-0 @ | |
| | | 0.125 in | |
| VESD | ESD Withstand Voltage Human Body Model (Note 1) | >2000 | V |
| | Machine Model (Note 2) | >200 | |
| ILatchup | Latchup Performance Above VCC and Below GND at 85°C | ±300 | mA |
| | (Note 3) | | |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1.Tested to EIA/JESD22-A114-A.
- 2.Tested to EIA/JESD22-A115-A.
- 3.Tested to EIA/JESD78.



RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|---------------------------------|--|-----|---------|------|
| Vcc | DC Supply Voltage (Referenced to GND) | 2.0 | 6.0 | V |
| VIN, | DC Input Voltage, Output Voltage (Referenced to GND) | 0 | VCC | V |
| Vout | | | | |
| TA | Operating Temperature, All Package Types | -40 | +85 | °C |
| t _r , t _f | Input Rise and Fall Time (Figure 3) | _ | NoLimt | ns |
| | | | (Note5) | |

^{4.}When VIN ~ 0.5 VCC, ICC >> quiescent current.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| | | VCC Guaranteed Limit | | | | |
|----------|----------------------|-----------------------------|-----|---------------|-------|------|
| Symbol | Parameter | Test Conditions | (V) | -40°C to 25°C | ≤85°C | Unit |
| VT+max | Maximum Positive | VOUT = 0.1 V | 2.0 | 1.5 | 1.5 | |
| | Going Input | IOUT ≤ 20 μA | 4.5 | 3.15 | 3.15 | V |
| | Threshold Voltage | | 6.0 | 4.2 | 4.2 | |
| | (Figure 5) | | | | | |
| VT+min | Minimum | VOUT = 0.1 V | 2.0 | 1.0 | 0.95 | |
| | Positive-Going Input | IOUT ≤ 20 μA | 4.5 | 2.3 | 2.25 | V |
| | Threshold Voltage | | 6.0 | 3.0 | 2.95 | |
| | (Figure 5) | | | | | |
| VT-max | Maximum | VOUT = VCC - 0.1 V | 2.0 | 0.9 | 0.95 | |
| | Negative-Going | IOUT ≤ 20 µA | 4.5 | 2.0 | 2.05 | V |
| | Input Threshold | | 6.0 | 2.6 | 2.65 | |
| | Voltage (Figure 5) | | | | | |
| VT–min | Minimum | VOUT = VCC - 0.1 V | 2.0 | 0.3 | 0.3 | |
| | Negative-Going | IOUT ≤ 20 μA | 4.5 | 0.9 | 0.9 | V |
| | Input Threshold | | 6.0 | 1.2 | 1.2 | |
| | Voltage (Figure 5) | | | | | |
| VHmax | Maximum Hysteresis | VOUT = 0.1 V or VCC – 0.1 V | 2.0 | 1.2 | 1.2 | |
| (Note 7) | Voltage | IOUT ≤ 20 μA | 4.5 | 2.25 | 2.25 | V |
| | (Figure 5) | | 6.0 | 3.0 | 3.0 | |
| VHmin | Minimum Hysteresis | VOUT = 0.1 V or VCC – 0.1 V | 2.0 | 0.2 | 0.2 | |
| (Note 7) | Voltage | IOUT ≤ 20 μA | 4.5 | 0.4 | 0.4 | V |
| | (Figure 5) | | 6.0 | 0.5 | 0.5 | |
| VOH | Minimum High-Level | VIN ≤ VT−min or VT+max | 2.0 | 1.9 | 1.9 | |
| | Output Voltage | IOUT ≤ 20 μA | 4.5 | 4.4 | 4.4 | |
| | | | 6.0 | 5.9 | 5.9 | V |
| | | VIN ≤ -VT-min or VT+max | | | | |
| | | IOUT ≤ 4.0 mA | 4.5 | 3.98 | 3.84 | |
| | | IOUT ≤ 5.2 mA | 6.0 | 5.48 | 5.34 | |

^{5.}Unused inputs may not be left open. All inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

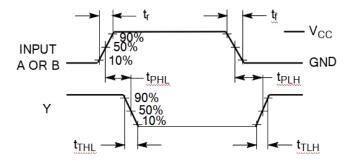


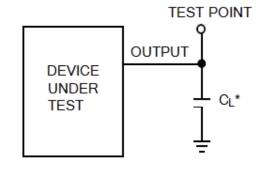
| VOL | Maximum Low-Level | VIN ≥VT+max | 2.0 | 0.1 | 0.1 | |
|-----|-------------------|-------------------------|-----|------|------|----|
| | Output Voltage | IOUT ≤ 20 μA | 4.5 | 0.1 | 0.1 | |
| | | | 6.0 | 0.1 | 0.1 | V |
| | | VIN≥ VT+max IOUT ≤ 4.0 | 4.5 | 0.26 | 0.33 | |
| | | mA | 6.0 | 0.26 | 0.33 | |
| | | IOUT ≤ 5.2 mA | | | | |
| IIN | Maximum Input | VIN = VCC or GND | 6.0 | ±0.1 | ±1.0 | μΑ |
| | Leakage Current | | | | | |
| ICC | Maximum Quiescent | VIN = VCC or GND | 6.0 | 2.0 | 20 | μΑ |
| | Supply Current | IOUT = 0 μA | | | | |
| | (per Package) | | | | | |

^{6.}VHmin > (VT+min) — (VT-max); VHmax = (VT+max) + (VT-min).

AC ELECTRICAL CHARACTERISTICS (CL = 50 pF, Input tr = tf = 6.0 ns)

| | | VCC | Guaranteed | Limit | |
|------------|---|-----------------------|---------------|-------|------|
| Symbol | Parameter | (V) | -40°C to 25°C | ≤85°C | Unit |
| tPLH, tPHL | Maximum Propagation Delay, Input A or B to Output | 2.0 | 125 | 155 | ns |
| | Y (Figures 3 and 4) | 4.5 | 25 | 31 | |
| | | 6.0 | 21 | 26 | |
| tTLH, tTHL | Maximum Output Transition Time, Any Output | 2.0 | 75 | 95 | ns |
| | (Figures 3 and 4) | 4.5 | 15 | 19 | |
| | | 6.0 | 13 | 16 | |
| Cin | Maximum Input Capacitance | _ | 10 | 10 | рF |
| | | Typical@25°C,VCC=5.0V | | | pF |
| CPD | Power Dissipation Capacitance(per Gate)(Note 10) | | | | |



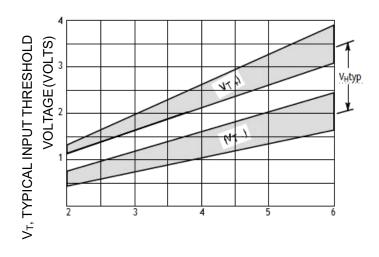


*Includes all probe and jig capacitance

Figure 3. Switching Waveforms

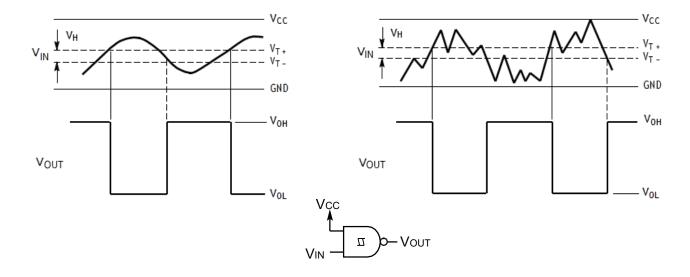
Figure 4. Test Circuit





V_{CC},POWER SUPPLY VOLTAE (VOLTS) VHtyp = (VT + typ) - (VT - typ)

Figure 5. Typical Input Threshold, VT+, VT- Versus Power Supply Voltage



(A)A SCHMITT TRIGGER SQUARES UP INPUTS WITH SLOW RISE AND FALL TIMES

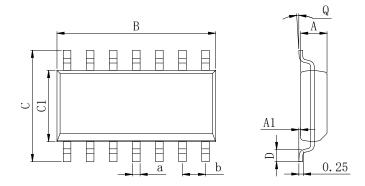
(B) A SCHMITT TRGGER OFFERS MAXIMUM NOSISE IMMUNITY

Figure 6. Typical Schmitt-Trigger Applications



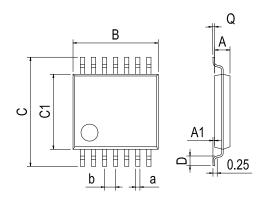
Physical Dimensions

SOP14



| Dimensions In Millimeters(SOP14) | | | | | | | | | |
|----------------------------------|------|------|------|------|------|------|----|------|----------|
| Symbol: | Α | A1 | В | С | C1 | D | Q | а | b |
| Min: | 1.35 | 0.05 | 8.55 | 5.80 | 3.80 | 0.40 | 0° | 0.35 | 4.07.000 |
| Max: | 1.55 | 0.20 | 8.75 | 6.20 | 4.00 | 0.80 | 8° | 0.45 | 1.27 BSC |

TSSOP14



| Dimensions In Millimeters(TSSOP14) | | | | | | | | | |
|------------------------------------|------|------|------|------|------|------|----|------|----------|
| Symbol: | Α | A1 | В | С | C1 | D | Q | а | b |
| Min: | 0.85 | 0.05 | 4.90 | 6.20 | 4.30 | 0.40 | 0° | 0.20 | 0.05.000 |
| Max: | 0.95 | 0.20 | 5.10 | 6.60 | 4.50 | 0.80 | 8° | 0.25 | 0.65 BSC |



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NLV74HC02ADR2G 74HC32S14-13 74LS133 74LVC1G32Z-7 74LVC1G86Z-7 NLV74HC14ADR2G NLV74HC20ADR2G
NLVVHC1G09DFT1G NLX2G86MUTCG 74LVC2G32RA3-7 74LVC2G00HD4-7 NL17SG02P5T5G 74LVC2G86HK3-7
NLV7SZ97DFT2G NLVVHC1G14DFT2G NLX1G99DMUTWG NLVVHC1G00DFT2G NLV7SZ57DFT2G NLV74VHC04DTR2G
NLV27WZ00USG NLU1G86CMUTCG NLU1G08CMUTCG NL17SZ32P5T5G NL17SZ00P5T5G NL17SH02P5T5G 74AUP2G00RA3-7
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